

## T495A106K006ATE1K5

T495, Tantalum, MnO2 Tantalum, 10 uF, 10%, 6.3 VDC, SMD, MnO2, Molded, Low ESR, 1.5 Ohms, 3216, Height Max = 1.8mm

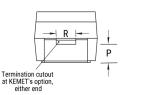
CATHODE (-) END VIEW



ANODE (+) END VIEW



SIDE VIEW



BOTTOM VIEW

Click	here	for	the	3D	model.
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Pac Pa Pa

Dimensions	
Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Н	1.6mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +0.2/-0.3mm
F	1.2mm +/-0.1mm
А	1.2mm MIN
В	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
Р	0.4mm REF
R	0.4mm REF
Х	0.1mm +/-0.1mm

Т

	0.1111117	0.111111
ckaging Specifications		
ackaging		T&R, 178mm
ackaging Quantity		2000

General Information	
Series	T495
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	58.6 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	10 uF
Capacitance Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
<b>Dissipation Factor</b>	6% 120Hz 25C
Failure Rate	N/A
Resistance	1500 mOhms (100kHz 25C)
Ripple Current	224 mA (rms, 100kHz 25C), 201.6 mA (rms, 85C), 89.6 mA (rms, 125C)
Leakage Current	0.6 uA (5min 25°C)

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